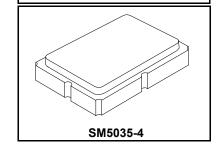




RFM products are now Murata products.

RO3164A-3

868.35 MHz SAW Resonator



- Ideal for European 868.35 MHz Transmitters
- · Very Low Series Resistance
- · Quartz Stability
- Surface-mount Ceramic Case
- Complies with Directive 2002/95/EC (RoHS)

The RO3164A-3 is a one-port surface-acoustic-wave (SAW) resonator packaged in a surface-mount ceramic case. It provides reliable, fundamental-mode quartz frequency stabilization of fixed-frequency transmitters operating at 868.35 MHz.

Absolute Maximum Ratings

Rating	Value	Units
CW RF Power Dissipation	+5	dBm
DC Voltage Between Terminals	±30	VDC
Case Temperature	-40 to +85	°C
Soldering Temperature (10 seconds / 5 cycles maximum)	260	°C

Electrical Characteristics

Characteristic		Sym	Notes	Minimum	Typical	Maximum	Units
Frequency at 25 °C	RO3164A-3	f _C	2,3,4,5	868.275		868.425	MHz
Tolerance from 868.35 MHz	RO3164A-3	Δf_{C}				±75	kHz
Insertion Loss		IL	2,5,6		1.3	2.0	dB
Quality Factor	Unloaded Q	Q _U	5,6,7		6600		
	50 Ω Loaded Q	Q _L			800		
Temperature Stability	Turnover Temperature	T _O		10	25	40	°C
	Turnover Frequency	f _O	6,7,8		f _C		kHz
	Frequency Temperature Coefficient	FTC			0.032		ppm/°C ²
Frequency Aging	Absolute Value during the First Year	fA	1		<±10		ppm/yr
DC Insulation Resistance bet	ween Any Two Terminals		5	1.0			ΜΩ
RF Equivalent RLC Model	Motional Resistance	R_{M}			13.8		Ω
	Motional Inductance	L_M	5, 6, 7, 9		16.8		μH
	Motional Capacitance	C _M			2.0		fF
	Shunt Static Capacitance	Co	5, 6, 9		1.8		pF
Test Fixture Shunt Inductance		L _{TEST}	2, 7		18.3		nH
Lid Symbolization (in addition to Lot and/or Date Codes)				8	314 // YYWWS	;	



CAUTION: Electrostatic Sensitive Device. Observe precautions for handling. NOTES:

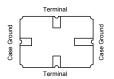
- Frequency aging is the change in f_C with time and is specified at +65 °C or less. Aging may exceed the specification for prolonged temperatures above +65 °C. Typically, aging is greatest the first year after manufacture, decreasing in subsequent years.
- The center frequency, f_C, is measured at the minimum insertion loss point, IL_{MIN}, with the resonator in the 50 Ω test system (VSWR ≤ 1.2:1). The shunt inductance, L_{TEST}, is tuned for parallel resonance with C_O at f_C. Typically, f_C and f_C are the resonance of the res
- f_{OSCILLATOR} or f_{TRANSMITTER} is approximately equal to the resonator f_C.

 One or more of the following United States patents apply: 4,454,488 and
- 4,010,197.
 Typically, equipment utilizing this device requires emissions testing and government approval, which is the responsibility of the equipment manufacturer.
 Unless noted otherwise, case temperature T_C = +25 ± 2 °C.
- Unless noted otherwise, case temperature 1_C = +25 ± 2 °C.
 The design, manufacturing process, and specifications of this device are subject to change without notice.
- 7. Derived mathematically from one or more of the following directly measured parameters: f $_C$, IL, 3 dB bandwidth, f $_C$ versus T $_C$, and C $_O$.
- 3. Turnover temperature, T_O , is the temperature of maximum (or turnover) frequency, f_O . The nominal frequency at any case temperature, T_C , may be calculated from: $f = f_O [1 FTC (T_O T_C)^2]$. Typically oscillator T_O is approximately equal to the specified resonator T_O .
- 9. This equivalent RLC model approximates resonator performance near the resonant frequency and is provided for reference only. The capacitance C_O is the static (nonmotional) capacitance between the two terminals measured at low frequency (10 MHz) with a capacitance meter. The measurement includes parasitic capacitance with "NC" pads unconnected. Case parasitic capacitance is approximately 0.05 pF. Transducer parallel capacitance can by calculated as: C_P ≈ C_O 0.05 pF.

Discontinued

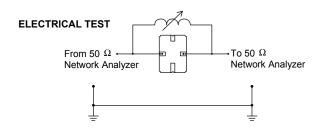
Electrical Connections

The SAW resonator is bidirectional and may be installed with either orientation. The two terminals are interchangeable and unnumbered. The callout NC indicates no internal connection. The NC pads assist with mechanical positioning and stability. External grounding of the NC pads is recommended to help reduce parasitic capacitance in the circuit.

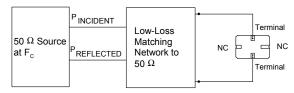


Typical Test Circuit

The test circuit inductor, L_{TEST} , is tuned to resonate with the static capacitance, C_{O} , at F_{C} .



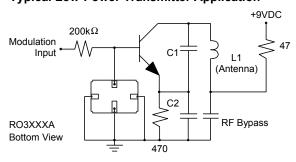
POWER TEST



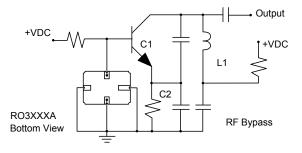
CW RF Power Dissipation = PINCIDENT - P REFLECTED

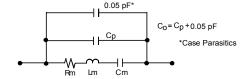
Typical Application Circuits

Typical Low-Power Transmitter Application



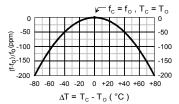
Typical Local Oscillator Applications



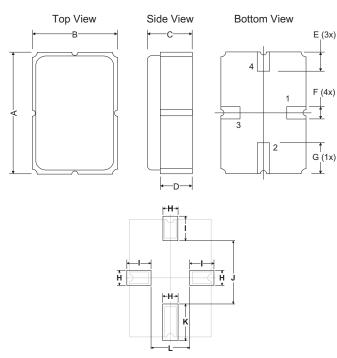


Temperature Characteristics

The curve shown on the right accounts for resonator contribution only and does not include LC component temperature contributions.



Case



PCB Land Pattern Top View

Dimensions	Millimeters		Inches			
Dimensions	Min	Nom	Max	Min	Nom	Max
Α	4.87	5.00	5.13	0.191	0.196	0.201
В	3.37	3.50	3.63	0.132	0.137	0.142
С	1.45	1.53	1.60	0.057	0.060	0.062
D	1.35	1.43	1.50	0.040	0.057	0.059
E	0.67	0.80	0.93	0.026	0.031	0.036
F	0.37	0.50	0.63	0.014	0.019	0.024
G	1.07	1.20	1.33	0.042	0.047	0.052
Н	-	1.04	-	-	0.041	-
I	-	1.46	-	-	0.058	-
J	-	0.50	-	-	0.019	-
K	-	1.05	-	-	0.041	-
L	-	1.44	-	-	0.057	-
М	-	0.71	-	-	0.028	-